NSN 5961-01-478-8778

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-478-8778 **Inclosure Material:** Plastic **Overall Length:** 3.050 millimeters **Terminal Length:** 1.110 millimeters **Overall Height:** 1.110 millimeters **Overall Width:** 2.500 millimeters **End Application:** M-1 abrams tank **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Base **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 40.0 collector to emitter voltage/static/base open and 75.0 collector to base voltage, dc and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 600.00 milliamperes peak forward surge current megahertz **Power Rating Per Characteristic:** 330.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 3 pin **Specification Data:** 19200-12467085 manufacturers source control Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

NSN 5961-01-478-8778 Transistor - Page 2 of 2



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